

exercise_sheet_1

Student Group

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4. Determine from the previous task the maximum current $I_{\max,S}$ for which the two power supplies must be designed at least.
(Note that for simple amplifiers the output current I_O is always less than or equal to the current I_S of the power supply).

Exercise 1.1.2 Microphone amplifier II

A voltage amplifier circuit is given, which shall amplify a microphone signal in such a way that a loudspeaker ($R_{LS} = 8.0 \Omega$) can be driven. Neither amplification nor the desired voltage at the loudspeaker is known. This amplifier circuit is internally protected against over-currents above $I_{\max, \text{amplifier}} = 5.0 \text{ A}$ by a fast fuse. It is known that no over-currents occur in the allowed voltage operation of 8.0Ω loudspeakers.

1. By what factor does the current change if a 4.0Ω loudspeaker is used instead of an 8.0Ω loudspeaker?

2. What effect does this have on the fuse?

Exercise 1.1.3 Wheatstone bridge circuit

Fig. 1: Wheatstone bridge circuit with a temperature sensor



Imagine that you work in the company “HHN Mechatronics & Robotics”. You are developing an IoT system that will be used in a harsh environment and will contain a rechargeable battery. The temperature of the battery must be monitored during operation and charging. If the temperature is too high, charging must be aborted or a warning issued. For the temperature measurement at the housing of the used lithium-ion cell [NCR18650](#) a measuring circuit is to be built up. A suggestion for the circuit is as follows:

1. Wheatstone bridge circuit with $R_1 = R_2 = R_3 = R_4 = 1.0k \Omega$.
2. Let the resistor R_4 be a PT1000 with a temperature coefficient $\alpha = 3850 \frac{\text{ppm}}{\text{K}}$.
3. For the other resistors, two components are chosen, that have an unknown temperature coefficient. According to the data sheet temperature coefficient is within $\alpha = \pm 100 \frac{\text{ppm}}{\text{K}}$.
4. The voltage source of the system generates a voltage of 5V with sufficient accuracy.
5. The determined voltage ΔU is amplified by a factor of 20 through another amplifier circuit, output as U_{O} , and further used by an analog-to-digital converter in a microcontroller¹⁾.

A short report is to be created; Tina TI is to be used as the analysis tool.

1. Create a problem description.

2. Rebuild the circuit in TINA TI and add this here. Take the following hint into account.

Hint

Use a simple resistor for the PT1000 in the simulation. With Tina TI, 27°C (room temperature) is selected as the reference temperature for the temperature curve. For the PT1000, the reference temperature is often 0°C (in practical applications, this should be checked in the data sheet). With Tina TI, the reference temperature can be changed by entering the value 27 under Temperature [C] in the properties (double-click on Resistor).

3. From the data sheet linked above, determine in what range from T_{\min} to T_{\max} may be charged and what temperature T_{\lim} may not be exceeded in any of the states.

4. First, for temperature invariant $R_1 = R_2 = R_3 = 1.0k \Omega$ and a temperature variable resistor R_4 , determine the voltage change ΔU over the temperature of $-30 \dots 70^\circ\text{C}$ in TINA TI. To do this, create a plot with ΔU as a function of temperature.
Read $\Delta U^0(T_{\min})$, $\Delta U^0(T_{\max})$, $\Delta U^0(T_{\lim})$, from the diagram and check the plausibility of the values by calculation.

5. Determine ΔU when the temperature dependence of R_1 , R_2 and R_3 is taken into account. To do this, create a suitable diagram with ΔU as a function of temperature in TINA TI.
At what voltages $U_O(T_{\min})$, $U_O(T_{\max})$ must the microcontroller intervene and disable charging?
At what value $U_A(T_{\lim})$ must a warning be issued?

6. Discuss the results

¹⁾ In real systems, an analog-to-digital converter would most likely not be used because of its relatively large power consumption for IoT applications. For Atmel chips, this is a few $10\ \mu\text{A}$, which adds up to a rapid battery drain over time.

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